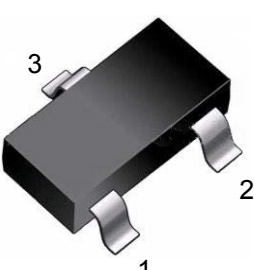


<p>PNP型 小功率 贴片开关三极管 PNP Switching Transistor SMD</p>	<p>HMBT3906 HMBT3906LT1 PNP, BEC General Purpose Transistors 对应其他工业型号 2N3906 MMBT3906 MMBT3906LT1 HM3906LT1</p>
<ul style="list-style-type: none"> <li>■ Excellent hFE linearity</li> <li>■ Low noise</li> <li>■ Complementary to HMBT3904</li> <li>■ Transistor Polarity: PNP</li> <li>■ Transistor pinout: BEC</li> <li>■ SOT-23 Package</li> <li>■ Marking Code: 2A</li> <li>■ hFE: 100~200, 200~300</li> </ul>	

<p style="text-align: center;">Inner circuit</p>  <p style="text-align: center;">SOT-23 内部结构</p>	<p style="text-align: center;">HMBT3906</p>  <p style="text-align: center;">SOT-23 管脚排列</p> <p style="text-align: center;">1. Base 2. Emitter 3. Collector</p>	<p style="text-align: center;">元件标识 (打印)</p>  <p style="text-align: center;">DEVICE MARKING</p>
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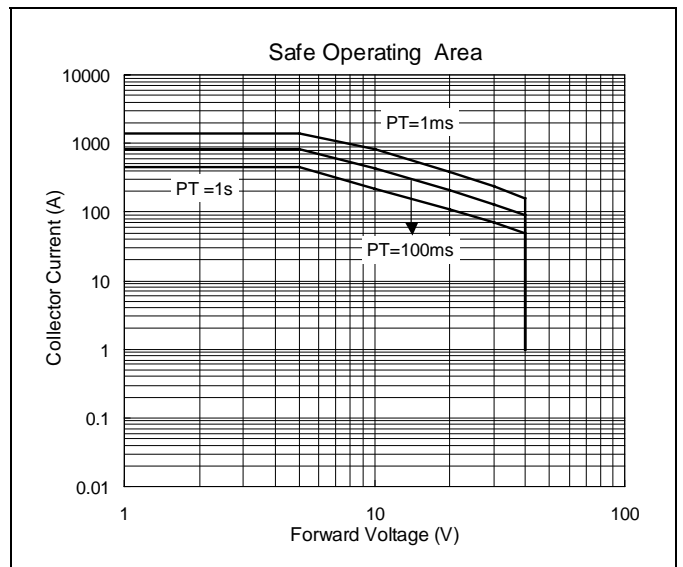
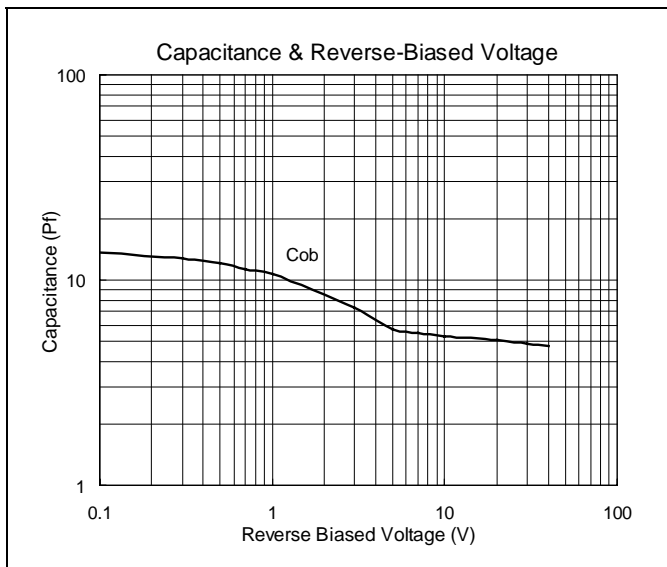
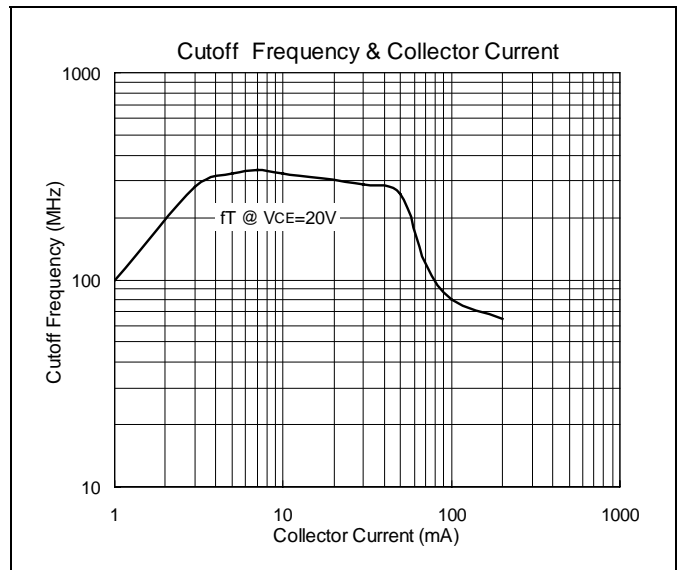
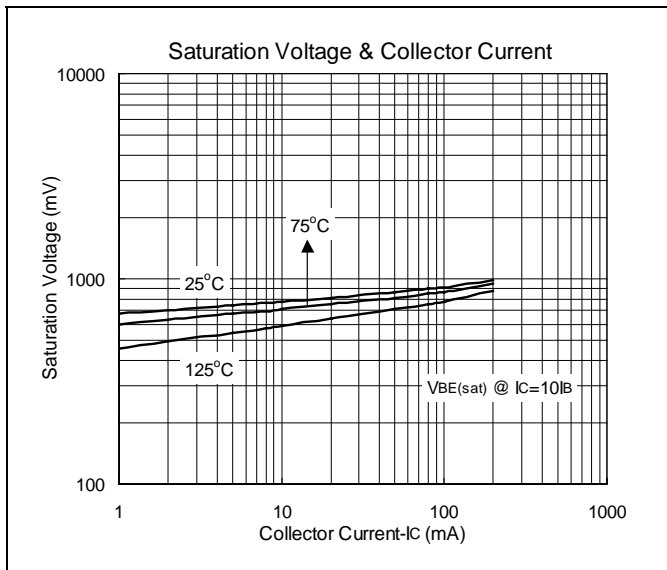
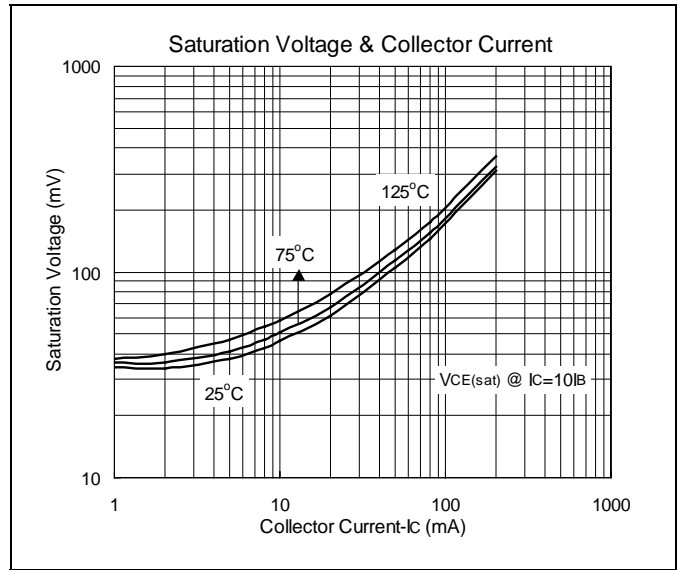
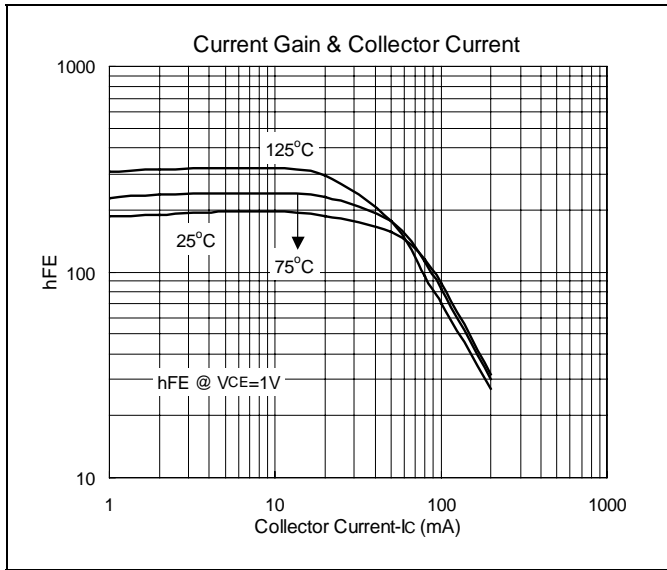
■ DEVICE MARKING 元件标识 (打印) 对应放大系数

HMBT3906	L	H
MARKING	2A	2A
hFE	100~200	200~300

■ MAXIMUM RATINGS 最大额定值

Characteristic 特性参数	Symbol 符号	Rating 额定值	Unit 单位
Collector-Base Voltage 集电极-基极电压	$V_{CBO}$	-40	V
Collector-Emitter Voltage 集电极-发射极电压	$V_{CEO}$	-40	
Emitter-Base Voltage 发射极-基极电压	$V_{EBO}$	-6.0	
Collector Current-Continuous 集电极电流-连续	$I_C$	-200	mA
Total Device Dissipation 总耗散功率	FR-5 Board (1)	225	mW
	Derate above 25°C 超过 25°C 递减	1.8	mW/°C
	Alumina Substrate 氧化铝衬底 (2) $T_A=25^\circ\text{C}$	300	mW
	Derate above 25°C 超过 25°C 递减	2.4	mW/°C
Thermal Resistance Junction to Ambient 热阻	$R_{\theta JA}$	417	°C/W
Junction Temperature 结温	$T_J$	150	°C
Storage Temperature Range 储存温度	$T_{stg}$	-55~+150	
Solder Temperature/Solder Time 焊接温度/焊接时间	$T/t$	260/10	°C/S

### Characteristics Curve





■ ELECTRICAL CHARACTERISTICS 电特性 ( $T_A=25^\circ\text{C}$  unless otherwise noted 如无特殊说明, 温度为 $25^\circ\text{C}$ )

Characteristic 特性参数	Test Condition 测试条件	Symbol 符号	Min 最小值	Typ 典型值	Max 最大值	Unit 单位
Collector-Emitter Breakdown Voltage 集电极-发射极击穿电压 (3)	$I_B=0, I_C=-1\text{mA}$	$V_{(BR)CEO}$	-40	--	--	V
Collector-Base Breakdown Voltage 集电极-基极击穿电压	$I_E=0, I_C=-10\mu\text{A}$	$V_{(BR)CBO}$	-40	--	--	
Emitter-Base Breakdown Voltage 发射极-基极击穿电压	$I_C=0, I_E=-10\mu\text{A}$	$V_{(BR)EBO}$	-6.0	--	--	
Base Cutoff Current 基极截止电流	$V_{CE}=-30\text{V}, V_{EB}=-3\text{V}$	$I_{BEX}$	--	--	-50	nA
Collector Cutoff Current 集电极截止电流	$V_{CE}=-30\text{V}, V_{EB}=-3\text{V}$	$I_{CEX}$	--	--	-50	
DC Current Gain 直流电流增益	$I_C=-0.1\text{mA}, V_{CE}=-1\text{V}$	hFE	40	--	--	
	$I_C=-1\text{mA}, V_{CE}=-1\text{V}$		70	--	--	
	$I_C=-10\text{mA}, V_{CE}=-1\text{V}$		100	--	300	
	$I_C=-50\text{mA}, V_{CE}=-1\text{V}$		60	--	--	
	$I_C=-100\text{mA}, V_{CE}=-1\text{V}$		30	--	300	
Collector-Emitter Saturation Voltage 集电极-发射极饱和压降	$I_C=-10\text{mA}, I_B=-1\text{mA}$	$V_{CE(sat)}$	--	--	0.25	V
	$I_C=-50\text{mA}, I_B=-5\text{mA}$		--	--	0.40	
Base-Emitter Saturation Voltage 基极-发射极饱和压降	$I_C=-10\text{mA}, I_B=-1\text{mA}$	$V_{BE(sat)}$	0.65	--	0.85	
	$I_C=-50\text{mA}, I_B=-5\text{mA}$		--	--	0.95	
Current-Gain-Bandwidth Product 电流增益-带宽乘积	$I_C=-10\text{mA}, V_{CE}=-20\text{V}$ $f=100\text{MHz}$	$f_T$	300	--	--	MHz
Collector Output Capacitance 输出电容	$V_{CB}=-5\text{V}, I_E=0, f=1\text{MHz}$	$C_{OB}$	--	--	4.0	pF
Input Capacitance 输入电容	$V_{EB}=-0.5\text{V}, I_C=0, f=1\text{MHz}$	$C_{ibo}$	--	--	8.0	
Input Impedance 输入阻抗	$I_C=-1\text{mA}, V_{CE}=-10\text{V}, f=1\text{kHz}$	hie	1.0	--	10	K $\Omega$
Voltage Feedback Ratio 电压反馈系数	$I_C=-1\text{mA}, V_{CE}=-10\text{V}, f=1\text{kHz}$	hre	0.5	--	8.0	$\times 10^{-4}$
Small-Signal Current Gain 小信号电流增益	$I_C=-1\text{mA}, V_{CE}=-10\text{V}, f=1\text{kHz}$	hFE	100	--	400	
Output Admittance 输出导纳	$I_C=-1\text{mA}, V_{CE}=-10\text{V}, f=1\text{kHz}$	hoe	1.0	--	40	$\mu\Omega$
Noise Figure 噪声系数	$I_C=-100\mu\text{A}, V_{CE}=-5\text{V}, R_s=1\text{K}\Omega, f=1\text{kHz}$	NF	--	--	5.0	db

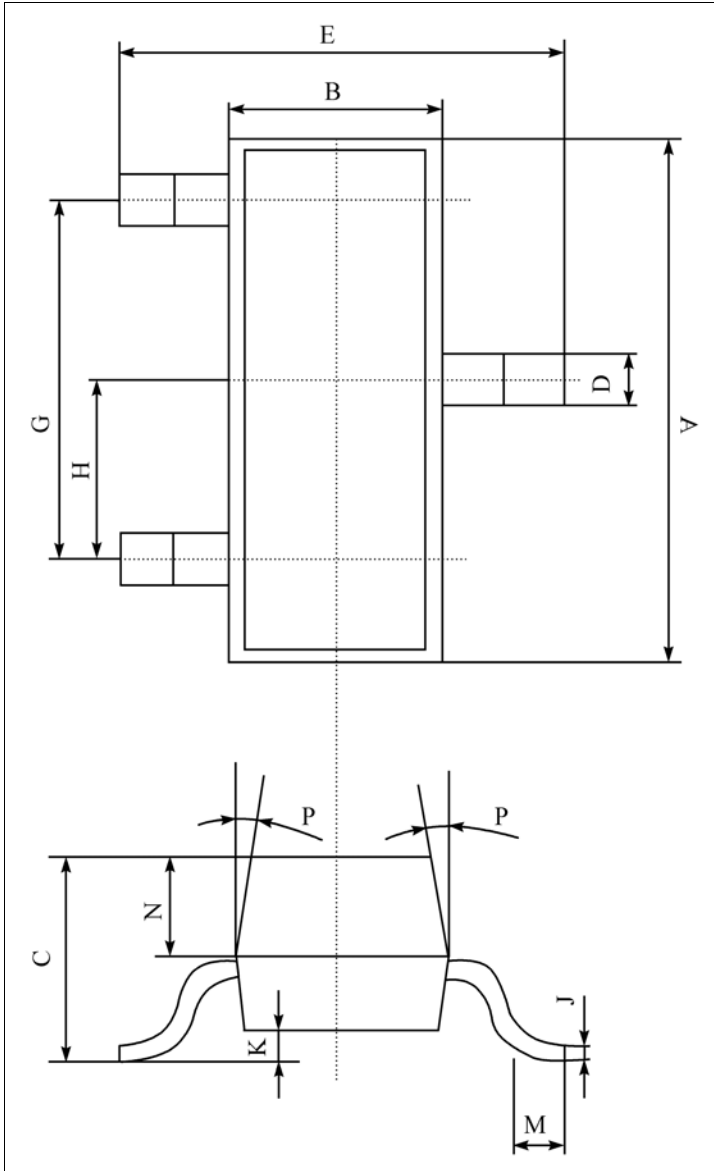
■ SWITCHING CHARACTERISTICS 開關特性

Characteristic 特性参数	Symbol 符号	Min 最小值	Max 最大值	Unit 单位
Delay Time 延迟时间	$V_{CC}=-30\text{V}, V_{BE(off)}=-0.5\text{V}$ $I_C=-10\text{mA}, I_{B1}=-1\text{mA}$	$t_d$	--	35
Rise Time 上升时间		$t_r$	--	35
Storage Time 储存时间	$V_{CC}=-30\text{V}, I_C=-10\text{mA}$ $I_{B1} = I_{B2} = -1\text{mA}$	$t_s$	--	225
Fall Time 下降时间		$t_f$	--	75

- FR-5 =  $1.0 \times 0.75 \times 0.062$  in.
- Alumina =  $0.4 \times 0.3 \times 0.024$  in. 99.5% alumina.
- Pulse Width  $\leq 300\mu\text{s}$ ; Duty Cycle  $\leq 2.0\%$ .
- Pulse Test: Pulse Width  $\leq 300\mu\text{s}$ ; Duty Cycle  $\leq 2.0\%$ .

■ DIMENSION 外形封装尺寸数据

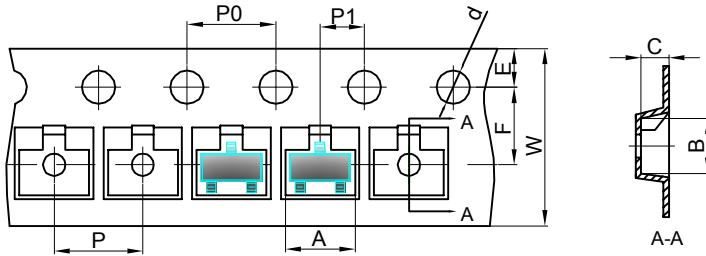
单位 (UNIT) : mm



序号	数值及公差
A	2.90±0.10
B	1.30±0.10
C	1.00±0.10
D	0.40±0.10
E	2.40±0.20
G	1.90±0.10
H	0.95±0.05
J	0.13±0.05
K	0.00-0.10
M	≥0.20
N	0.60±0.10
P	7±2°
<b>Packing</b> SOT-23 包装规格 SMD片式表面贴封装 包装方式: 载带卷盘包装 Tape & Reel, 3Kpcs/Reel 每卷数量3000只 (3Kpcs/Reel) 每盒数量45000只 (45Kpcs/BOX) 每箱数量180000只 (180Kpcs/Cartons)	

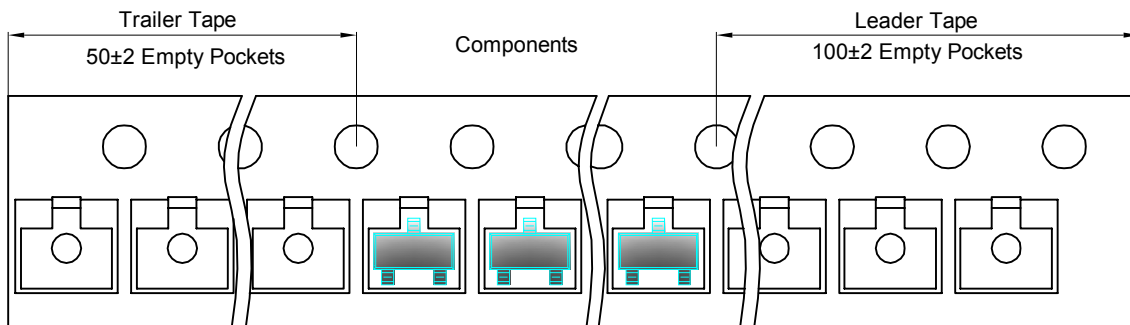
## SOT-23 Tape and reel

### SOT-23 Embossed Carrier Tape

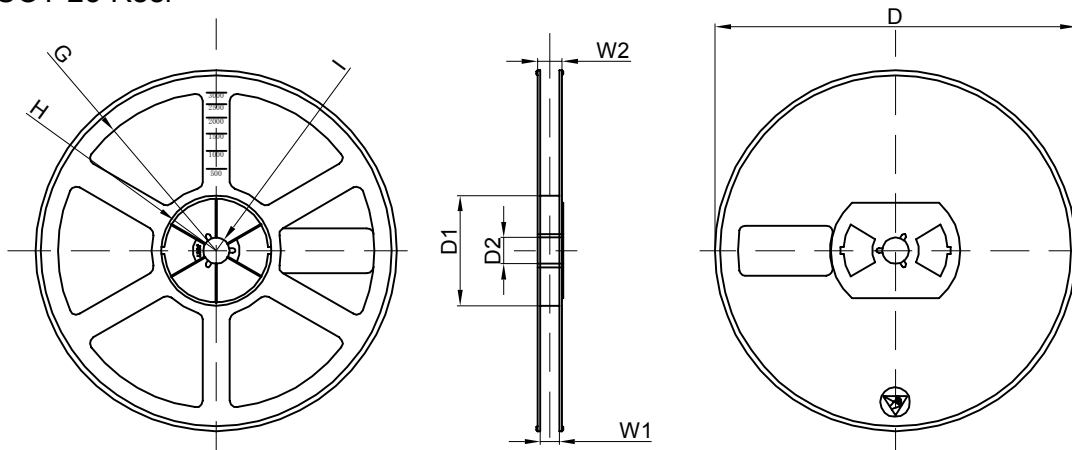


Dimensions are in millimeter										
Pkg type	A	B	C	d	E	F	P0	P	P1	W
SOT-23	3.15	2.77	1.22	Ø1.50	1.75	3.50	4.00	4.00	2.00	8.00

### SOT-23 Tape Leader and Trailer



### SOT-23 Reel



Dimensions are in millimeter								
Reel Option	D	D1	D2	G	H	I	W1	W2
7" Dia	Ø178.00	54.40	13.00	R78.00	R25.60	R6.50	9.50	12.30

REEL	Reel Size	Box	Box Size(mm)	Carton	Carton Size(mm)	G.W.(kg)
3000 pcs	7 inch	30,000 pcs	203×203×195	120,000 pcs	438×438×220	